

# Reliability Qualification Report

for

**8Gb 1.8V Parallel NAND FLASH  
with Pb/Halogen Free  
(Automotive)**

Issued Date: April 07, 2023

## **Contents :**

**1. Title**

**2. Product and Package Information**

**3. Result Summary**

**4. Accelerated Lifetime Simulation Tests (Including Failure Rate Estimation)**

**5. Accelerated Lifetime Simulation Tests (Endurance & Data Retention)**

**6. Accelerated Environment Stress Tests**

**7. Electrical Verification Tests (Electrostatic Discharge & Latch-up)**

## 1. Title

This report describes the reliability and qualification data of Alliance product listed below.

The qualification and reliability tests have been completed successfully based on AEC-Q100.

## 2. Product and Package Information

|                              |   |
|------------------------------|---|
| Product code                 | : AS9F18G08SA-45BAN                                   |
| Operating temperature        | : AEC-Q100 Grade 2 (-40°C to +105°C)                  |
| Package type                 | : FBGA 63B (9 x 11mm, 1.0T)                           |
| Solder ball                  | : SAC1205N (98.25% Sn / 1.2% Ag / 0.5% Cu / 0.05% Ni) |
| Flammability                 | : UL-V0   |
| Thermal resistance(Theta Ja) | : 16 °C/W   |

## 3. Result Summary

|                           |  |
|---------------------------|--|
| Lifetime Simulation Tests | : Passed ELFR & HTOL                           |
| Environment Stress Tests  | : Passed All Tests                             |
| ESD & Latch-up            | : Passed HBM 2000V, CDM 500V & Latch-up ±200mA |

## 4. Accelerated Lifetime Simulation Tests

| Group                                 | Test Item / Conditions  | Test Method  | Duration or Level | Result         |                           | Notes      |
|---------------------------------------|---|--------------|-------------------|----------------|---------------------------|------------|
|                                       |   |              |                   | Number of Lots | Failed Q'ty / Tested Q'ty |            |
| Accelerated Lifetime Simulation Tests | <b>Early Life Failure Rate</b><br>Grade 1 : 125°C, 2.05V Dynamic stress   | AEC Q100-008 | 48 hours          | 3              | 0 / 2400<br>(Passed)      | 1, 2       |
|                                       | <b>High Temperature Operating Life</b><br>Grade 1 : 125°C, 2.05V Dynamic stress,<br>Read cycling with CKBD pattern<br><u>Preconditioning : 10k Endurance test at high temperature</u> | AEC Q100-005 | 1000 hours        | 3              | 0 / 231<br>(Passed)       | 1, 2, 3, 4 |

**Note :**

- 1) All electrical tests at different temperatures are performed before and after each item based on AEC-Q100 Rev-H.
- 2) "Dynamic stress" means continuous memory operation like read or write function.
- 3) High temperature program/erase endurance cycling is performed as preconditioning before the test.
- 4) CKBD means "Checkerboard" pattern.

## \* Failure Rate Estimation

**Estimation Condition :**

User Operating Temperature : 55°C

User Operating Voltage : Worst case (Maximum Operating Voltage in the Datasheet)

Confidence Level : 60%

$$AF_{OVERALL} = AF_T * AF_V = 77.9 * 2.2 = 173.5$$

Early Life (Ea = 0.7 eV, β = 8) : 45.9 FITs

Inherent Life (Ea = 0.7 eV, β = 8) : 22.9 FITs

## 5. Accelerated Lifetime Simulation Tests (Endurance & Data Retention)

| Group                                 | Test Item / Conditions  | Test Method                 | Duration or Level | Result         |                           | Notes |
|---------------------------------------|---|-----------------------------|-------------------|----------------|---------------------------|-------|
|                                       |   |                             |                   | Number of Lots | Failed Q'ty / Tested Q'ty |       |
| Accelerated Lifetime Simulation Tests | <b>Endurance @ High Temperature</b><br>85°C, 1.95V, Program/Read "0"/Erase/Read "1" cycling   | AEC Q100-005<br>JESD22-A117 | 10k cycles        | 3              | 0 / 231<br>(Passed)       | 1     |
|                                       | <b>High Temperature Data Retention</b><br>125°C, All bit cells programmed<br><u>Preconditioning : 10k Endurance test at high temperature above</u>  |                             | 100 hours         | 3              | 0 / 231<br>(Passed)       | 1, 2  |
|                                       | <b>Endurance @ High Temperature</b><br>85°C, 1.95V, Program/Read "0"/Erase/Read "1" cycling   |                             | 100k cycles       | 3              | 0 / 231<br>(Passed)       | 1     |
|                                       | <b>High Temperature Data Retention</b><br>125°C, All bit cells programmed<br><u>Preconditioning : 100k Endurance test at high temperature above</u> |                             | 10 hours          | 3              | 0 / 231<br>(Passed)       | 1, 3  |
|                                       | <b>Endurance at Low Temperature</b><br>25°C, 1.95V, Program/Read "0"/Erase/Read "1" cycling   |                             | 100k cycles       | 3              | 0 / 231<br>(Passed)       | 1     |
|                                       | <b>Low Temperature Data Retention</b><br>25°C, All bit cells programmed<br><u>Preconditioning : 100k Endurance test at low temperature above</u>    |                             | 1000 hours        | 3              | 0 / 231<br>(Passed)       | 1     |
|                                       | <b>High Temperature Data Retention</b><br>125°C, All bit cells programmed<br><u>Preconditioning : 10k Endurance test at low temperature above</u>   |                             | 100 hours         | 3              | 0 / 231<br>(Passed)       | 1     |

**Note :**

- 1) All electrical tests at different temperatures are performed before and after each item based on AEC-Q100 Rev-H.
- 2) 100 hours bake at 125°C temperature is equivalent to 10 years at 55°C.
- 3) 10 hours bake at 125°C temperature is equivalent to 1 year at 55°C.

## 6. Accelerated Environment Stress Tests

| Group                                | Test Item / Conditions   | Test Method | Duration or Level                            | Result         |                           | Notes |
|--------------------------------------|--|-------------|--|----------------|---------------------------|-------|
|                                      |  |             |  | Number of Lots | Failed Q'ty / Tested Q'ty |       |
| Accelerated Environment Stress Tests | <b>Preconditioning</b><br>Bake : 125°C<br>Soak : 30°C, 60% RH<br>Reflow : 260°C          | J-STD-020   | Level 3<br>24 hours<br>192 hours<br>3 cycles | 3              | 0 / 738<br>(Passed)       | 1     |
|                                      | <b>Biased HAST</b><br>110°C, 85% RH, 1.95V(V <sub>CC</sub> max)                          | JESD22-A110 | 264 hours                                    | 3              | 0 / 231<br>(Passed)       | 1, 2  |
|                                      | <b>Unbiased HAST</b><br>110°C, 85% RH  | JESD22-A118 | 264 hours                                    | 3              | 0 / 231<br>(Passed)       | 1, 2  |
|                                      | <b>Temperature Cycling</b><br>Grade 1 : -65°C to 150°C                                   | JESD22-A104 | 500 cycles                                   | 3              | 0 / 231<br>(Passed)       | 1, 2  |
|                                      | <b>Power Temperature Cycling</b><br>Grade 2 : -40°C to 105°C, 1.95V(V <sub>CC</sub> max) | JESD22-A105 | 1000 cycles                                  | 1              | 0 / 45<br>(Passed)        | 1, 2  |
|                                      | <b>High Temperature Storage Life</b><br>Grade 2 : 150°C                                  | JESD22-A103 | 500 hours                                    | 1              | 0 / 45<br>(Passed)        | 1     |

**Note :**

- 1) All electrical tests at different temperatures are performed before and after each item based on AEC-Q100 Rev-H.
- 2) Preconditioning is performed before the test.

## 7. Electrical Verification Tests (Electrostatic Discharge & Latch-up)

| Group                         | Test Item / Conditions                    | Test Method  | Duration or Level | Result         |                           | Notes |
|-------------------------------|---|--------------|-------------------|----------------|---------------------------|-------|
|                               |   |              |                   | Number of Lots | Failed Q'ty / Tested Q'ty |       |
| Electrical Verification Tests | ESD Human Body Model                      | AEC Q100-002 | 500V              | 1              | 0 / 9<br>(Passed)         | 1, 2  |
|                               | ESD Human Body Model                      |              | 1000V             | 1              | 0 / 9<br>(Passed)         | 1, 2  |
|                               | ESD Human Body Model                      |              | 2000V             | 1              | 0 / 9<br>(Passed)         | 1, 2  |
|                               | ESD Charged Device Model                  | AEC Q100-011 | 250V              | 1              | 0 / 3<br>(Passed)         | 1, 2  |
|                               | ESD Charged Device Model                  |              | 500V              | 1              | 0 / 3<br>(Passed)         | 1, 2  |
|                               | Latch-Up (I-test)<br>- Test at 105°C      | AEC Q100-004 | ±200mA            | 1              | 0 / 6<br>(Passed)         | 1, 3  |
|                               | Latch-Up (Overvoltage)<br>- Test at 105°C |              | 3V                | 1              | 0 / 3<br>(Passed)         | 1, 3  |

**Note :**

- 1) All electrical tests at different temperatures are performed before and after each item based on AEC-Q100 Rev-H.
- 2) HBM & CDM tests are performed at room temp.
- 3) Latch-up tests are performed at 105°C.